TOSHIBA Field Effect Transistor Silicon N Channel Junction Type

# 2SK369

### For Low Noise Audio Amplifier Applications

Unit: mm

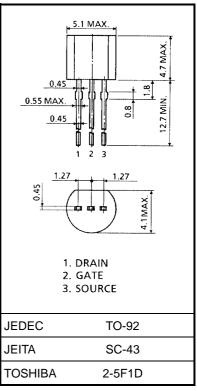
- Suitable for use as first stage for equalizer and MC head amplifiers.
- High  $|Y_{fs}|$ :  $|Y_{fs}| = 40$  mS (typ.) (VDS = 10 V, VGS = 0, IDSS = 5 mA)
- High breakdown voltage:  $V_{GDS} = -40 \text{ V (min)}$
- Super low noise: NF = 1.0dB (typ.)

 $(V_{DS} = 10 \text{ V}, I_{D} = 5 \text{ mA}, f = 1 \text{ kHz}, R_{G} = 100 \Omega)$ 

• High input impedance:  $I_{GSS} = -1 \text{ nA (max) (V}_{GS} = -30 \text{ V)}$ 

# **Maximum Ratings (Ta = 25°C)**

Characteristics	Symbol	Rating	Unit
Gate-drain voltage	$V_{GDS}$	-40	V
Gate current	IG	10	mA
Drain power dissipation	P <sub>D</sub>	400	mW
Junction temperature	Tj	125	°C
Storage temperature range	T <sub>stg</sub>	-55~125	°C



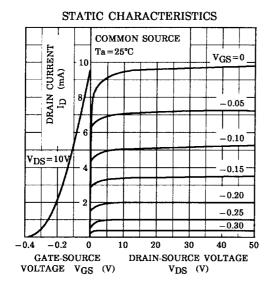
Weight: 0.21 g (typ.)

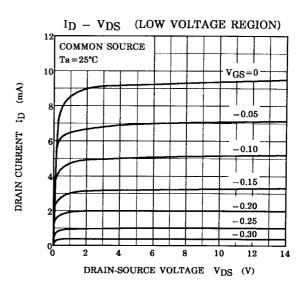
## **Electrical Characteristics (Ta = 25°C)**

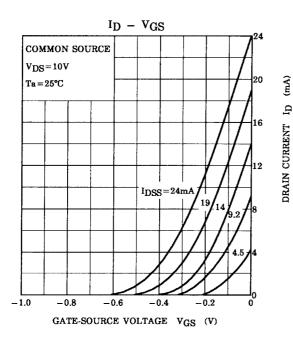
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate cut-off current	I <sub>GSS</sub>	$V_{GS} = -30 \text{ V}, V_{DS} = 0$	_	_	-1.0	nA
Gate-drain breakdown voltage	V (BR) GDS	$V_{DS} = 0$ , $I_G = -100 \mu A$	-40	_	_	V
Drain current	I <sub>DSS</sub> (Note 1)	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0	5.0	_	30	mA
Gate-source cut-off voltage	V <sub>GS</sub> (OFF)	$V_{DS} = 10 \text{ V}, I_D = 0.1  \mu\text{A}$	-0.3	_	-1.2	V
Forward transfer admittance	Y <sub>fs</sub>	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ kHz}, \\ (I_{DSS} = 5 \text{ mA})$	25	40	_	mS
Input capacitance	C <sub>iss</sub>	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	75	_	pF
Reverse transfer capacitance	C <sub>rss</sub>	$V_{GD} = -10 \text{ V}, I_D = 0, f = 1 \text{ MHz}$	_	15	_	pF
Noise figure (Note 2)	NF (1)	$V_{DS}$ = 10 V, $R_G$ = 100 $\Omega$ , $I_D$ = 5 mA, $f$ = 100 Hz		5	10	- dB
	NF (2)	$V_{DS}$ = 10 V, $R_G$ = 100 $\Omega$ , $I_D$ = 5 mA, $f$ = 1 kHz	_	1	2	

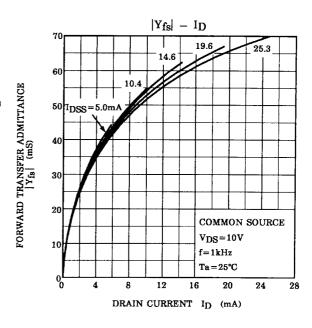
Note 1: IDSS classification GR: 5.0~10.0 mA, BL: 8.0~16.0 mA, V: 14.0~30.0 mA

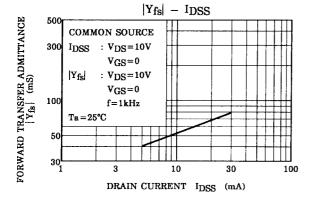
Note 2: Use this in the low voltage region (VDS < 15 V) for low noise applications.

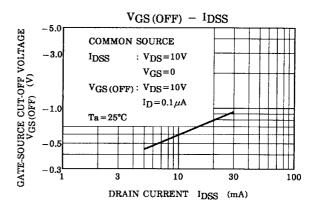


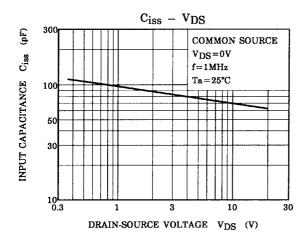


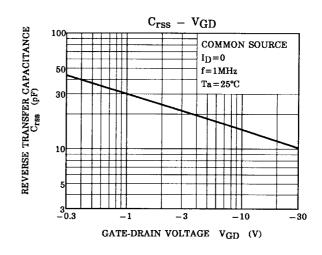


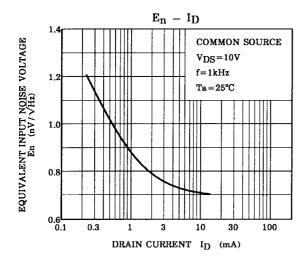


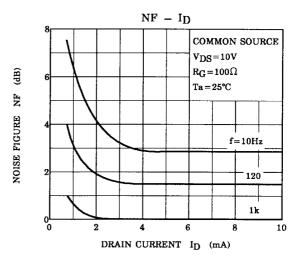


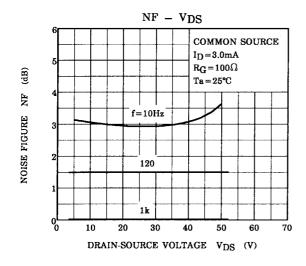


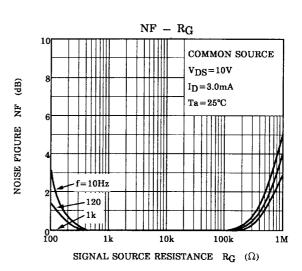


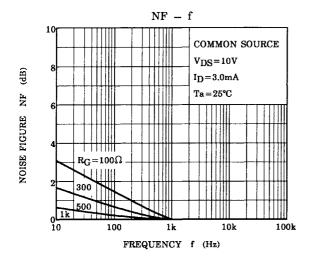


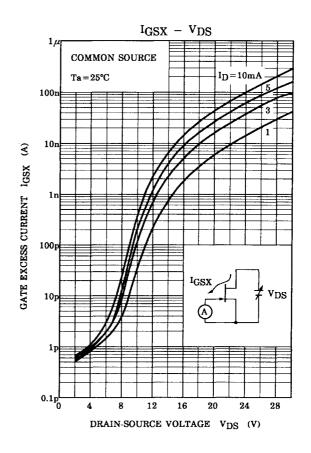


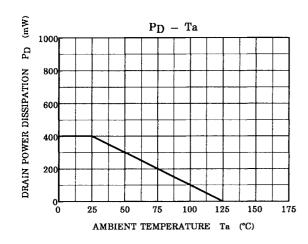












#### **RESTRICTIONS ON PRODUCT USE**

000707EAA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
  In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The information contained herein is presented only as a guide for the applications of our products. No
  responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other
  rights of the third parties which may result from its use. No license is granted by implication or otherwise under
  any intellectual property or other rights of TOSHIBA CORPORATION or others.

5

The information contained herein is subject to change without notice.

This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.